onsemi

Dual Switching Diode BAS16DXV6

Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

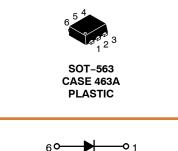
| Rating | Symbol | Max | Unit |
|---|------------------------|-----|------|
| Continuous Reverse Voltage | V _R | 100 | V |
| Recurrent Peak Forward Current | ١ _F | 200 | mA |
| Peak Forward Surge Current Pulse Width = 10 μs | I _{FM(surge)} | 500 | mA |

THERMAL CHARACTERISTICS

| Characteristic (One Junction Heated) | Symbol | Max | Unit |
|---|-----------------------------------|-------------|-------------|
| Total Device Dissipation (Note 1) T _A = 25°C Derate above 25°C | P _D | 357 2.9 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient (Note 1) | $R_{\theta JA}$ | 350 | °C/W |
| Characteristic (Both Junctions Heated) | Symbol | Мах | Unit |
| Total Device Dissipation (Note 1) T _A = 25°C Derate above 25°C | P _D | 500 4.0 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient (Note 1) | $R_{\theta JA}$ | 250 | °C/W |
| Junction and Storage Temperature | T _J , T _{stg} | -55 to +150 | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-4 @ Minimum Pad





MARKING DIAGRAM



A6 = Specific Device Code

M = Date Code

= Pb–Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|---------------|----------------------|-----------------------|
| BAS16DXV6T1G | SOT–563 (Pb–Free) | 4000 / Tape & Reel |
| SBAS16DXV6T1G | SOT–563 (Pb–Free) | 4000 / Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|---|-----------------|------------------|----------------------------|------|
| Forward Voltage $(I_F = 1.0 \text{ mA})$ $(I_F = 10 \text{ mA})$ $(I_F = 50 \text{ mA})$ $(I_F = 150 \text{ mA})$ | V _F | - - - - | 715 855 1000 1250 | mV |
| Reverse Current $(V_R = 100 V)$ $(V_R = 75 V, T_J = 150^{\circ}C)$ $(V_R = 25 V, T_J = 150^{\circ}C)$ | Ι _R | | 1.0 50 30 | μΑ |
| Capacitance (V _R = 0, f = 1.0 MHz) | CD | - | 2.0 | pF |
| Reverse Recovery Time ($I_F = I_R = 10 \text{ mA}, R_L = 50 \Omega$) (Figure 1) | t _{rr} | - | 6.0 | ns |
| Stored Charge (I _F = 10 mA to V _R = 6.0 V, R _L = 500 Ω) (Figure 2) | QS | - | 45 | PC |
| Forward Recovery Voltage ($I_F = 10 \text{ mA}, t_r = 20 \text{ ns}$) (Figure 3) | V _{FR} | - | 1.75 | V |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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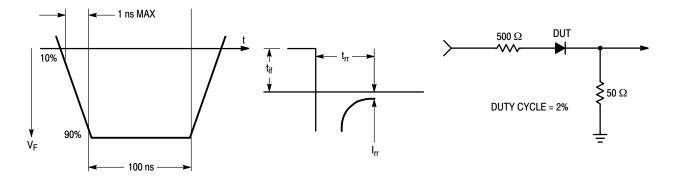


Figure 1. Reverse Recovery Time Equivalent Test Circuit

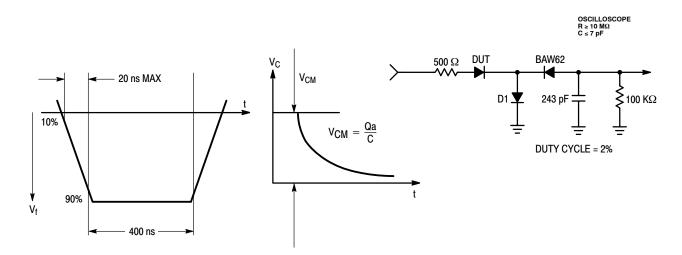


Figure 2. Stored Charge Equivalent Test Circuit

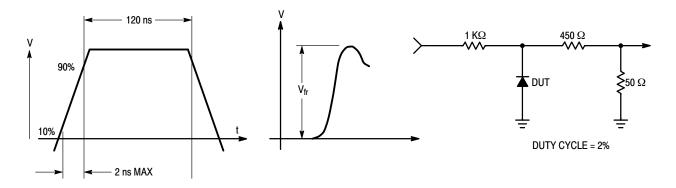


Figure 3. Forward Recovery Voltage Equivalent Test Circuit

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TYPICAL CHARACTERISTICS

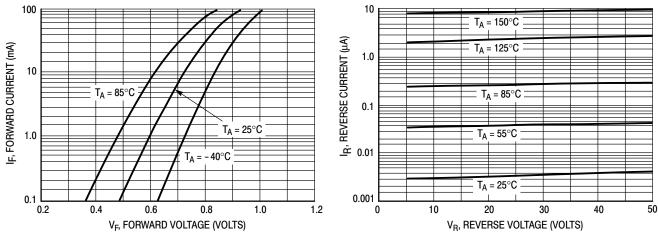


Figure 4. Forward Voltage



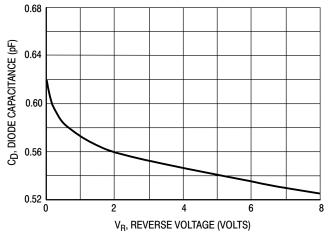
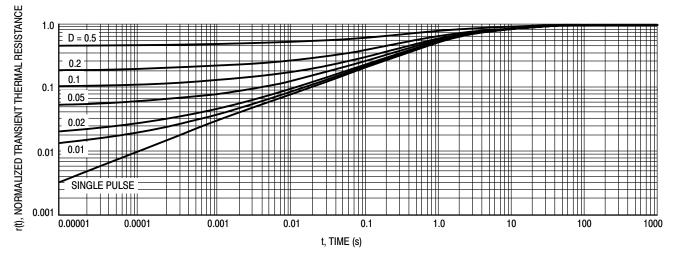
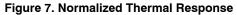


Figure 6. Capacitance





MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



ONSEM

| SOT-563-6 1.60x1.20x0.55, 0.50P CASE 463A | | | | | | | | |
|---|---|--|--|----------------------------|---|--|--|-------------------------|
| | | | ISSUE J | | | | - | |
| | | | | | | | DA | TE 15 FEB 2024 |
| | | | NOTES: 1. DIMENSION Y14.5-2 | | ND TOLE | RANCING | CONFORM | I TO ASME |
| | | | ALL DIM MAXIMUN THICKNE | ENSION , / LEAD | THICKNE MUM LE. | SS INCLU AD THICK | JDES LEAD | D FINISH THE MINIMUM |
| | DA | А — | | . Г | | M | ILLIMETE | RS |
| | B | ~ | | L | DIM | MIN. | NDM. | MAX. |
| | | | | | Α | 0.50 | 0.55 | 0.60 |
| PIN 1 6 | 5 4 1 | | | | b | 0.17 | 0.22 | 0.27 |
| REFERENCE | +E | | | | С | 0.08 | 0.13 | 0.18 |
| | 2 3 | | | | D | 1.50 | 1.60 | 1.70 |
| | ⊥ ∟ - → → 6X b | | | | E | 1.10 | 1.20 | 1.30 |
| | ⊕ 0.08@ |) A B | ; | | е | | 0.50 BSC | |
| | | | SIDE VIEW | | Н | 1.50 | 1.60 | 1.70 |
| <u>101</u> | | : | | | L | 0.10 | 0.20 | 0.30 |
| | | STYLE 3 | | | 0.30 | | | 〈 0.45 |
| PIN 1. EMITTER 1 PIN 2. BASE 1 3. COLLECTOR 2 4. EMITTER 2 5. BASE 2 6. COLLECTOR 1 | 1. EMITTER 1 2. EMITTER 2 3. BASE 2 4. COLLECTOR 2 5. BASE 1 6. COLLECTOR 1 | PIN 1. CATHODE 2. CATHODE 3. ANODE// 4. CATHODE 5. CATHODE 6. ANODE// | 2 1 ANDDE 2 2 2 2 2 | RECC | | | 1 1 0.50 0.50 0.50 0.50 | 4 |
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| DESCRIPTION: | SOT-563-6 1. | 60x1.20x0.55, | 0.50P | | | | | PAGE 1 OF 1 |

SOT-563-6 1.60x1.20x0.55, 0.50P

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